General Purpose Peak EMI Reduction IC

Functional Description

PCS3P7303A is a versatile, 3.3 V / 2.5 V Peak EMI reduction IC based on TIMING SAFETM technology. PCS3P7303A accepts an input clock either from a Crystal or from an external reference (AC or DC coupled to XIN / CLKIN) and locks on to it delivering a 1x modulated clock output. PCS3P7303A has a Frequency Selection (FS) control that facilitates selecting one of the two frequency ranges within the operating frequency range. Refer to the *Frequency Selection* Table for details.

PCS3P7303A has an SSEXTR pin to select different deviations depending upon the value of an external resistor connected between SSEXTR and GND. Modulation Rate (MR) control selects two different Modulation Rates.

PPCS3P7303A operates from a 3.3 V / 2.5 V supply and is available in an 8–pin TSSOP and 8L 2 mm x 2 mm WDFN packages.

Application

PCS3P7303A is targeted for many applications including USB and SATA.

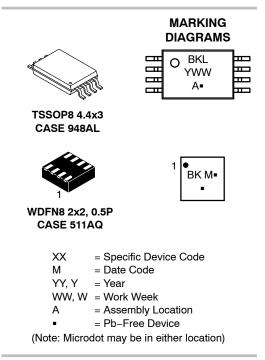
General Features

- 1x LVCMOS Peak EMI Reduction
- Input Frequency:
 - ◆ 10 MHz 70 MHz @ 2.5 V
 - 10 MHz 80 MHz @ 3.3 V
- Output Frequency:
 - 10 MHz 70 MHz @ 2.5 V
 - 10 MHz 80 MHz @ 3.3 V
- Analog Deviation Selection
- ModRate Selection Option
- Supply Voltage: $2.5 V \pm 0.2 V$
 - $3.3 \text{ V} \pm 0.3 \text{ V}$
- 8-pin TSSOP, 8L 2 mm x 2 mm WDFN (TDFN) Packages
- The First True Drop-in Solution
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

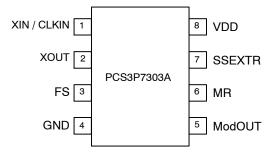


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ORDERING INFORMATION

See detailed ordering and shipping information on page 7 of this data sheet.

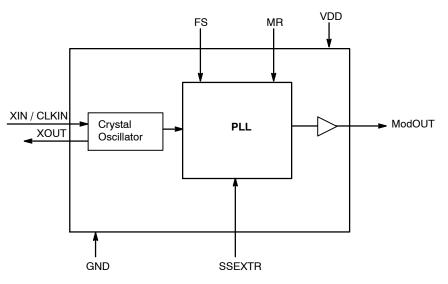


Figure 1. Block Diagram

Table 1. PIN DESCRIPTION

Pin #	Pin Name	Туре	Description	
1	XIN / CLKIN	Input	Crystal connection or External reference clock input.	
2	XOUT	Output	Crystal connection. If using an external reference, this pin should be left open.	
3	FS	Input	Frequency Select. Pull LOW to select Low Frequency range. Selects High Frequency range when pulled HIGH. Has an internal pull-up resistor. (See <i>Frequency Selection table</i> for details.)	
4	GND	Power	Ground.	
5	ModOUT	Output	Buffered Modulated clock output.	
6	MR	input	Modulation Rate Select. When LOW selects Low Modulation Rate. Selects High Modulation Rate when pulled HIGH. Has an internal pull-down resistor.	
7	SSEXTR	Input	Analog Deviation Selection through external resistor to GND.	
8	VDD	Power	2.5 V / 3.3 V supply Voltage.	

Table 2. FREQUENCY SELECTION TABLE

VDD (V)	FS	Frequency (MHz)
0.5	0	10 – 35
2.5	1	30 – 70
0.0	0	10 – 40
3.3	1	30 – 80

Table 3. ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Rating	Unit
VDD, V _{IN}	Voltage on any input pin with respect to Ground	-0.5 to +4.6	V
T _{STG}	Storage temperature	−65 to +125	°C
Ts	Max. Soldering Temperature (10 sec)	260	°C
TJ	Junction Temperature	150	°C
T _{DV}	Static Discharge Voltage (As per JEDEC STD22- A114-B)	2	kV

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Table 4. OPERATING CONDITIONS

Parameter	Description		Max	Unit
VDD	Supply Voltage	2.3	3.6	V
T _A	Operating Temperature (Ambient Temperature)	-25	+85	°C
CL	Load Capacitance		10	pF
C _{IN}	Input Capacitance		7	pF

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

Table 5. DC ELECTRICAL CHARACTERISTICS FOR 2.5 V

Parameter	Description	Test	Conditions	Min	Тур	Max	Units
VDD	Supply Voltage			2.3	2.5	2.7	V
VIL	Input LOW Voltage					0.7	V
V _{IH}	Input HIGH Voltage			1.7			V
IIL	Input LOW Current	V _{IN} = 0 V				-50	μΑ
I _{IH}	Input HIGH Current	V _{IN} = V _{DD}				50	μΑ
V _{OL}	Output LOW Voltage	I _{OL} = 8 mA	I _{OL} = 8 mA			0.6	V
V _{OH}	Output HIGH Voltage	I _{OH} = -8 mA		1.8			V
I _{CC}	Static Supply Current	XIN / CLKIN pu	lled low			500	μΑ
I _{DD}	Dynamic Supply Current	Unloaded FS = 0; @ 10 MHz				5	mA
		Output	FS = 1; @ 70 MHz			12	
Z _O	Output Impedance				45		Ω

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Table 6. SWITCHING CHARACTERISTICS FOR 2.5 V

Parameter		Test Conditions	3	Min	Тур	Max	Units
Input Frequency (Note 1) /	FS = 0			10		35	MHz
ModOUT	FS = 1			30		70	
Duty Cycle (Notes 2, 3)	Measured at V _{DD} /2			45	50	55	%
Output Rise Time (Notes 2, 3)	Measured between 2	Measured between 20% to 80%			1.75	2.5	nS
Output Fall Time (Notes 2, 3)	Measured between 8	Measured between 80% to 20%			1.0	1.6	nS
Cycle-to-Cycle Jitter	Unloaded output	FS = 0	10 MHz		±450	±600	pS
(Note 3)			35 MHz		±125	±250	
	FS = 1 30 MHz				±225	±350	
	70 MHz				±150	±300	
PLL Lock Time (Note 3)	Stable power supply,	valid clock pres	ented on XIN / CLKIN			3	mS

1. Functionality with Crystal is guaranteed by design and characterization. Not 100% tested in production.

All parameters are specified with 10 pF loaded outputs.
Parameter is guaranteed by design and characterization. Not 100% tested in production.

Table 7. DC ELECTRICAL CHARACTERISTICS FOR 3.3 V

Parameter	Description	Test	Conditions	Min	Тур	Max	Units
VDD	Supply Voltage				3.3	3.6	V
V _{IL}	Input LOW Voltage					0.8	V
V _{IH}	Input HIGH Voltage			2.0			V
Ι _{ΙL}	Input LOW Current	V _{IN} = 0 V	V _{IN} = 0 V			-50	μA
I _{IH}	Input HIGH Current	V _{IN} = V _{DD}				50	μA
V _{OL}	Output LOW Voltage	I _{OL} = 8 mA	I _{OL} = 8 mA			0.4	V
V _{OH}	Output HIGH Voltage	I _{OH} = -8 mA		2.4			V
I _{CC}	Static Supply Current	XIN / CLKIN pu	Illed low			700	μA
I _{DD}	Dynamic Supply Current	Unloaded	FS = 0; @ 10 MHz			7	mA
		Output	FS = 1; @ 80 MHz			20	
ZO	Output Impedance				35		Ω

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Table 8. SWITCHING CHARACTERISTICS FOR 3.3 V

Parameter		Test Condition	S	Min	Тур	Max	Units
Input Frequency (Note 1) /	FS = 0	FS = 0				40	MHz
ModOUT	FS = 1			30		80	
Duty Cycle (Notes 2, 3)	Measured at $V_{DD}/2$			45	50	55	%
Output Rise Time (Notes 2, 3)	Measured between 2	Measured between 20% to 80%			1.3	2	nS
Output Fall Time (Notes 2, 3)	Measured between 8	Measured between 80% to 20%			0.9	1.3	nS
Cycle-to-Cycle Jitter	Unloaded output	Unloaded output FS = 0 10 MHz			±450	±600	pS
(Note 3)		40 MHz			±125	±250	
	FS = 1 30 MHz				±225	±350	
	80 MHz			±125	±250		
PLL Lock Time (Note 3)	Stable power supply	valid clock pres	sented on XIN / CLKIN			3	mS

4. Functionality with Crystal is guaranteed by design and characterization. Not 100% tested in production.

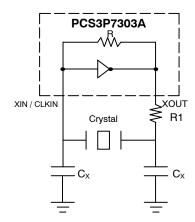
5. All parameters are specified with 10 pF loaded outputs.

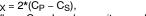
6. Parameter is guaranteed by design and characterization. Not 100% tested in production.

Table 9. TYPICAL CRYSTAL SPECIFICATIONS

Fundamental AT Cut Parallel Resonant Crystal				
Nominal frequency	25 MHz			
Frequency tolerance	±50 ppm or better at 25°C			
Operating temperature range	-25°C to +85°C			
Storage temperature	-40°C to +85°C			
Load capacitance (C _P)	18 pF			
Shunt capacitance	7 pF maximum			
ESR	25 Ω			

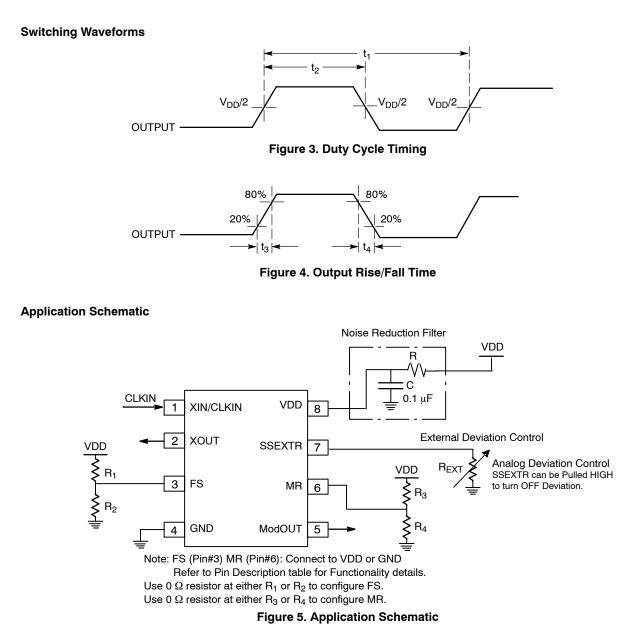
NOTE: CL is the Load Capacitance and R1 is used to prevent oscillations at overtone frequency of the Fundamental frequency.





 $\label{eq:C_p} \begin{array}{l} C_X = 2^\star (C_P - C_S), \\ \mbox{Where } C_P = \mbox{Load capacitance of crystal from crystal vendor datasheet}. \end{array}$ C_S = Stray capacitance due to C_{IN} , PCB, Trace, etc.





Charts

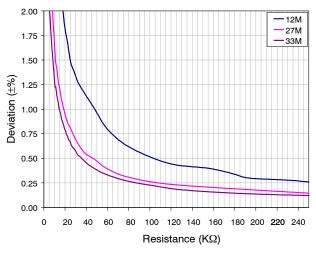


Figure 6. Deviation vs. Resistance (FS = 0, MR = 0)

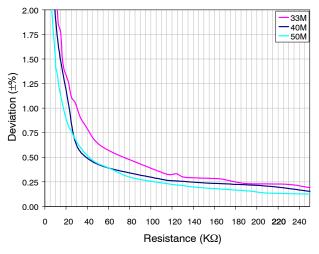


Figure 8. Deviation vs. Resistance (FS = 1, MR = 0)

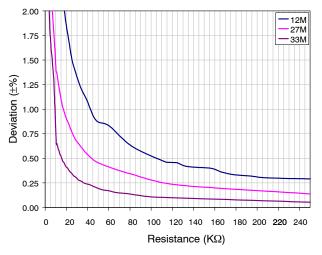


Figure 7. Deviation vs. Resistance (FS = 0, MR = 1)

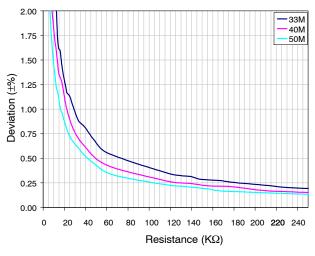


Figure 9. Deviation vs. Resistance (FS = 1, MR = 1)

NOTE: Device to Device variation of Deviation is $\pm 10\%$ (0°C to 70°C) and $\pm 25\%$ (-25°C to +85°C)

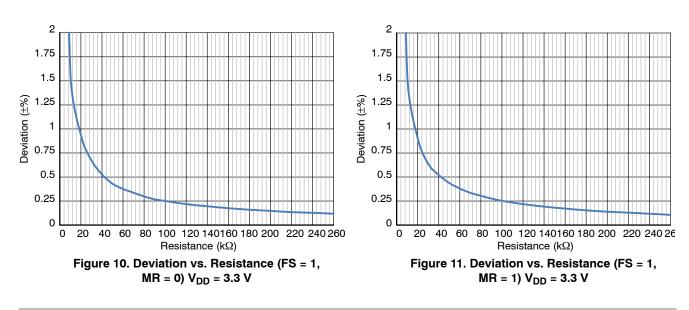


Table 10. ORDERING INFORMATION

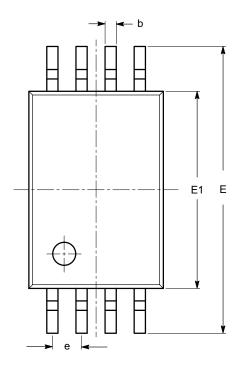
Part Number	Marking	Temperature	Package	Shipping [†]
PCS3P7303AG-08TR	BKL	–25°C to +85°C	8-pin TSSOP (Pb-Free)	Tape & Reel
PCS3P7303AG-08TT	BKL	–25°C to +85°C	8-pin TSSOP (Pb-Free)	Tube
PCS3P7303AG-08CR	ВК	–25°C to +85°C	8L WDFN (2 mm x 2 mm) (Pb-Free)	Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

NOTE: A "microdot" placed at the end of last row of marking or just below the last row toward the center of package indicates Pb-Free.

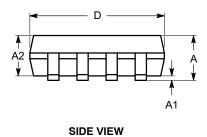
PACKAGE DIMENSIONS

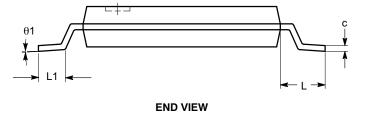
TSSOP8, 4.4x3 CASE 948AL ISSUE O



SYMBOL	MIN	NOM	MAX	
А			1.20	
A1	0.05		0.15	
A2	0.80	0.90	1.05	
b	0.19		0.30	
с	0.09		0.20	
D	2.90	3.00	3.10	
E	6.30	6.40	6.50	
E1	4.30	4.40	4.50	
е		0.65 BSC		
L	1.00 REF			
L1	0.50	0.60	0.75	
θ	0°		8°	

TOP VIEW

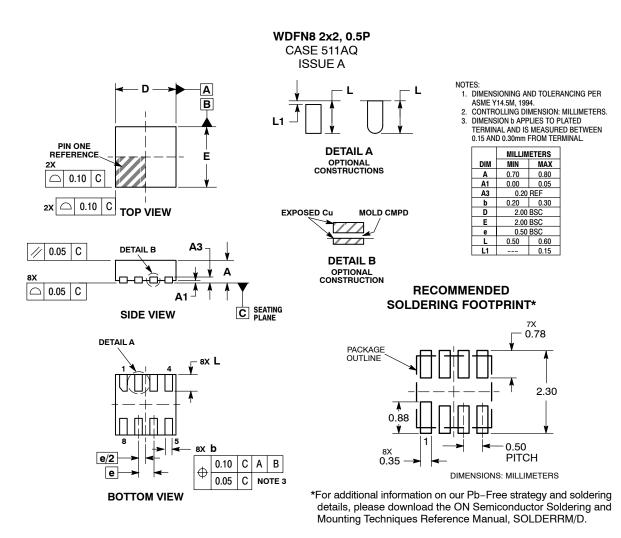




Notes:

All dimensions are in millimeters. Angles in degrees.
Complies with JEDEC MO-153.

PACKAGE DIMENSIONS



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